

SSCT15V11L3

1-Line Uni-directional TVS Diode

Description

The SSCT15V11L3 is an uni-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The SSCT15V11L3 complies with the IEC 61000-4-2 (ESD) with \pm 30kV air and \pm 30kV contact discharge. It is assembled into an ultra-small 1.6x1.0x0.5mm lead-free DFN package. The small size and high ESD surge protection make SSCT15V11L3 an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

Features

- ♦ Ultra small package:1.6x1.0x0.5mm
- ♦ Protects one date or power line
- ♦ Working voltage:15V
- ♦ 2-pin leadless package
- ♦ Complies with following standards:
 - -IEC61000-4-2(ESD) ± 30 Kv(contact), ± 30 kV(air)
 - -IEC61000-4-5(Lightning) 60A(8/20μs)
- ♦ RoHS Compliant

• PIN configuration



Top view



Marking

Applications

- ♦ Mobile Phones
- ♦ Battery Protection
- ♦ Power Line Protection
- ♦ Vbat pin for Mobile Devices
- ♦ Hand Held Portable Applications

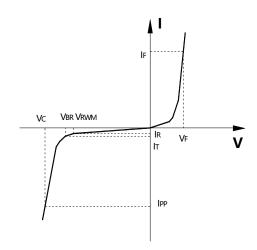
Mechanical Characteristics

- ♦ Package:DFN1610-2L(1.6x1.0x0.5mm)
- ♦ Case Material: "Green" Molding Compound.
- ♦ UL Flammability Classification Rating 94V-0
- ♦ Moisture Sensitivity: Level 3 per J-STD-020
- ♦ Terminal Connections: See Diagram Below
- ♦ Marking Information: See Below



• Electronic Parameter

Symbol	Parameter			
V_{RWM}	Peak Reverse Working Voltage			
I_R	Reverse Leakage Current @ V _{RWM}			
V_{BR}	Breakdown Voltage @ I _T			
I _T	Test Current			
IPP	Maximum Reverse Peak Pulse Current			
$V_{\rm C}$	Clamping Voltage @ IPP			
P _{PPP}	Peak Pulse Power			
С	Junction Capacitance			



• Absolute maximum rating @TA=25°C

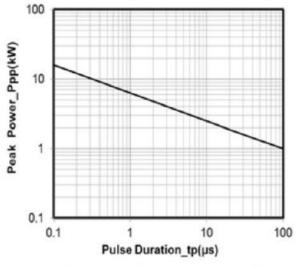
Symbol	Parameter	Value	Units
VECD	ESD Rating per IEC61000-4-2:Contact	±30	I/A/
VESD	Air	±30	KV
P _{PPP}	Peak Pulse Power (8/20μs)	2000	W
IPP	Peak Pulse Current (8/20 μ s)	60	A
T _{STG}	Storage Temperature	-55/+150	°C
T _J	Operating Temperature	-55/+125	°C

• Electrical Characteristics @TA=25°C

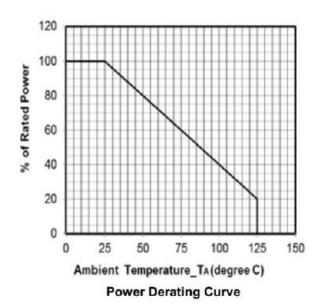
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Peak Reverse Working Voltage	V_{RWM}	Any I/O to Ground			15	V
D	17	It = 1mA			77	
Breakdown Voltage	V_{BR}	Any I/O to Ground	16.5			V
Reverse Leakage Current	I_R	VRWM =15V, T=25 °C			0.1	μΑ
Forward Voltage	VF	IF=10mA		1.0	1.2	V
Clamping Voltage	V_{C1}	IPP = $10A$, $tP = 8/20\mu s$			22	V
Clamping Voltage	V_{C2}	IPP= $60A$, $tP = 8/20 \mu s$			32	V
Junction Capacitance	C _J	VR = 0V, $f = 1MHz$,			450	pF

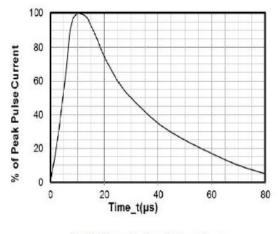


• Typical Performance Characteristics(Ta=25°C unless otherwise Specified)

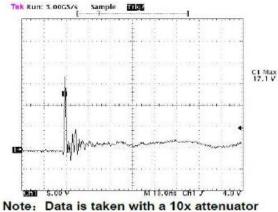


Junction Capacitance vs. Reverse Voltage





8 X 20µs Pulse Waveform

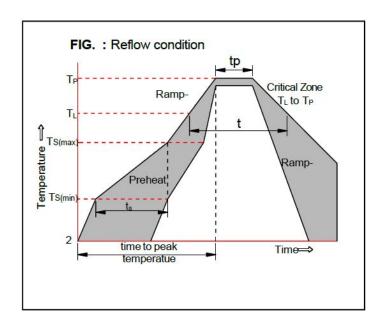


Note: Data is taken with a 10x attenuator ESD Clamping Voltage +8 kV Contact per IEC61000-4-2



• Soldering Parameters

Reflow Con	ndition	Pb-Free assembly	
		(see as bellow)	
	-Temperature Min (Ts(min))	+150°C	
Pre Heat	-Temperature Max(Ts(max))	+200°C	
	-Time (Min to Max) (ts)	60-180 secs.	
Average ramp up rate (Liquid us Temp (TL) to peak)		3°C/sec. Max	
Ts(max) to TL - Ramp-up Rate		3°C/sec. Max	
Reflow	-Temperature(TL)(Liquid us)	+217°C	
Kellow	-Temperature(tL)	60-150 secs.	
Peak Temp (Tp)		+260(+0/-5)°C	
Time within 5°C of actual Peak Temp (tp)		30 secs. Max	
Ramp-down Rate		6°C/sec. Max	
Time 25°C to Peak Temp (TP)		8 min. Max	
Do not exceed		+260°C	





• Package Information

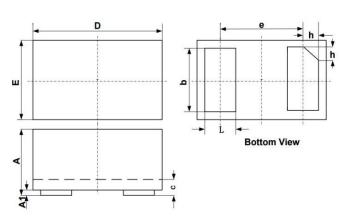
Ordering Information

Device	Package	Qty per Reel	Reel Size
SSCT15V11L3	DFN1610-2L	3000	7 Inch

Mechanical Data

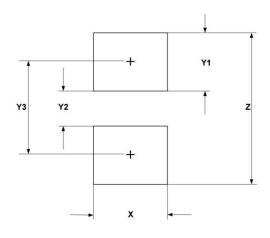
Case: DFN1610-2L

Case Material: Molded Plastic. UL Flammability



	DIMENSIONS					
SYM		MILLIME	TERS	ERS INCHES		
STIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.45	0.50	0.55	0.018	0.020	0.022
A1	0.00	0.02	0.05	0.000	0.001	0.002
b	0.75	0.80	0.85	0.030	0.032	0.034
С	0.10	0.15	0.20	0.004	0.006	0.007
D	1.55	1.60	1.65	0.062	0.064	0.066
е		1.10 BSC			0.044	BSC
Е	0.95	1.00	1.05	0.038	0.040	0.042
L	0.35	0.40	0.45	0.014	0.016	0.018
h	0.15	0.20	0.25	0.006	0.008	0.010

Suggested Land Pattem



	DIMENSIONS				
SYM	MILLIMETERS	INCHES			
X	1.00	0.040			
Y1	0.62	0.025			
Y2	0.60	0.024			
Y3	1.22	0.049			
Z	1.85	0.074			



DISCLAIMER

AFSEMI RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. AF SEMI DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICIENCE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

THE GRAPHS PROVIDED IN THIS DOCUMENT ARE STATISTICAL SUMMARIES BASED ON A LIMITED NUMBER OF SAMPLES AND ARE PROVIDED FOR INFORMATIONAL PURPOSE ONLY. THE PERFORMANCE CHARACTERISTICS LISTED IN THEM ARE NOT TESTED OR GUARANTEED. IN SOME GRAPHS, THE DATA PRESENTED MAY BE OUTSIDE THE SPECIFIED OPERATING RANGE (E.G., OUTSIDE SPECIFIED POWER SUPPLY RANGE) AND THEREFORE OUTSIDE THE WARRANTED RANGE.